2SC4223



800V/1.5A Switching Regulator Applications

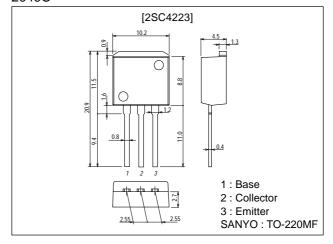
Features

- · High breakdown voltage, high reliability.
- · High-speed switching ($t_f=0.1\mu s$ typ).
- · Wide ASO.
- · Adoption of MBIT process.
- · Suitable for sets whose height is restricted.

Package Dimensions

unit:mm

2049C



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		1100	V
Collector-to-Emitter Voltage	VCEO		800	V
Emitter-to-Base Voltage	V _{EBO}		7	V
Collector Current	lС		1.5	Α
Collector Current (Pulse)	I _{CP}	PW≤300μs, duty cycle≤10%	5	Α
Base Current	IB		0.8	Α
Collector Dissipation	D	Ta=25°C	1.65	W
	PC	Tc=25°C	40	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	I _{CBO}	V _{CB} =800V, I _E =0			10	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =5V, I _C =0			10	μΑ

Continued on next page.

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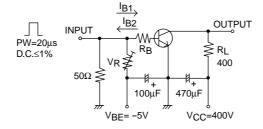
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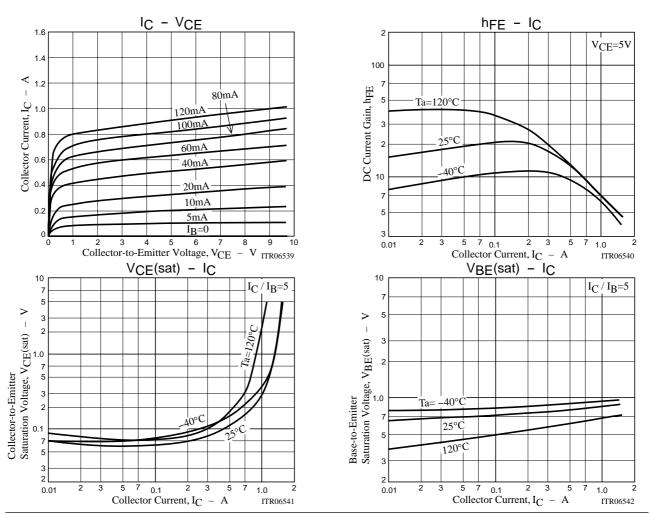
Parameter	Symbol	Conditions	Ratings			Unit
Farameter	Symbol	Conditions		typ	max	Offic
DC Current Gain	h _{FE} 1	V _{CE} =5V, I _C =0.1A			40*	
DC Current Gain	h _{FE} 2	V _{CE} =5V, I _C =0.5A				
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =0.1A		15		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		35		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =0.75A, I _B =0.15A			2.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =0.75A, I _B =0.15A			1.5	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =1mA, I _E =0				V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =5mA, R _{BE} =∞				V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =1mA, I _C =0				V
Collector-to-Emitter Sustain Voltage	V _{CEX(sus)}	I _C =0.75A, I _{B1} =-I _{B2} =0.15A, L=5mH, clamped				V
Turn-ON Time	ton	I _C =1A, I _{B1} =0.2A, I _{B2} =-0.4A, R _L =400Ω, V _{CC} =400V			0.5	μs
Storage Time	t _{stg}	I _C =1A, I _{B1} =0.2A, I _{B2} =-0.4A, R _L =400Ω, V _{CC} =400V			3.0	μs
Fall Time	tf	I _C =1A, I _{B1} =0.2A, I _{B2} =-0.4A, R _L =400Ω, V _{CC} =400V			0.3	μs

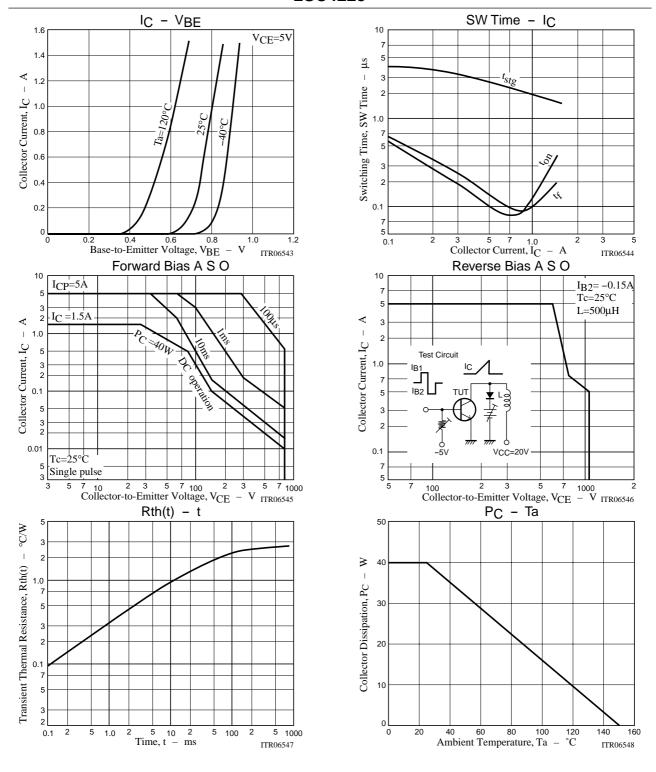
^{*}: The $h_{FE}1$ of the 2SC4223 is classified as follows. When specifying the $h_{FE}1$ rank, specify two ranks or more in principle.

Rank	K	L	М	
hFE	10 to 20	15 to 30	20 to 40	

Switching Time Test Circuit







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